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The importance of intramolecular conductivity in three dimensional molecular solids†

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Recent years have seen tremendous progress towards understanding the relation between the molecular structure and function of organic field effect transistors. The metrics for organic field effect transistors, which are characterized by mobility and the on/off ratio, are known to be enhanced when the intermolecular interaction is strong and the intramolecular reorganization energy is low. While these requirements are adequate when describing organic field effect transistors with simple and planar aromatic molecular components, they are insufficient for complex building blocks, which have the potential to localize a carrier on the molecule. Here, we show that intramolecular conductivity can play a role in controlling device characteristics of organic field effect transistors made with macrocycle building blocks. We use two isomeric macrocyclic semiconductors that consist of perylene diimides linked with bithiophenes and find that the *trans*-linked macrocycle has a higher mobility than the *cis*-based device. Through a combination of single molecule junction conductance measurements of the components of the macrocycles, control experiments with acyclic counterparts to the macrocycles, and analyses of each of the materials using spectroscopy, electrochemistry, and density functional theory, we attribute the difference in electron mobility of the OFETs created with the two isomers to the difference in intramolecular conductivity of the two macrocycles.

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Introduction

Understanding how molecular structure impacts mobility in organic field effect transistors (OFETs) has garnered much attention in recent years.^{1–6} Small, flat aromatic molecules, such as linear acenes, have been widely used as the active layer in organic semiconductors due to their relatively high carrier mobilities in both films and single crystal devices. The high carrier mobilities are attributed to strong intermolecular interaction amongst adjacent molecules and low intramolecular reorganization energy.^{7–9} While these two requirements govern charge transport for small, flat aromatic molecules, they are insufficient for complex, three dimensional molecules. In the latter, carriers can become localized, impeding transport. Examples of three dimensional molecular prototype are fullerenes and fullerene derivatives,¹⁰ which are n-type materials used in OFETs,^{11–13} organic photovoltaics

(OPVs),^{14–16} and organic photodetectors (OPDs).^{16,17} However, fullerenes are difficult to synthesize and functionalize, and their optical properties cannot be easily tuned. This prompts the search for alternatives that both absorb visible light and retain structural features, such as a three-dimensional shape.^{18–22}

Here, we study a sub-class of three dimensional, organic materials called conjugated macrocycles. Conjugated macrocycles possess several structural and electronic advantages over acyclic molecules: (1) their contorted structure can facilitate intermolecular contact and charge transport;^{19,23} (2) they contain no end groups that can act as trap sites in linear molecules;^{24–27} (3) they often absorb more visible light than linear molecules;^{28,29} and (4) their intramolecular cavities can act as a host for electronic guests.^{30–35} We create OFETs with three dimensional molecular solids made from macrocyclic organic semiconductors illustrated in Fig. 1, and describe the role of intramolecular conductivity on their performance. We find that intramolecular conductivity has an appreciable effect on the semiconductors' transport properties. While electronically active macrocycles have been used in organic devices such as transistors, photovoltaics and detectors in recent years,^{23,29,33,36–41} the impact of molecular structure on device performance is an ongoing field of research.⁴¹ Our macrocycles were designed to enhance intermolecular interactions through

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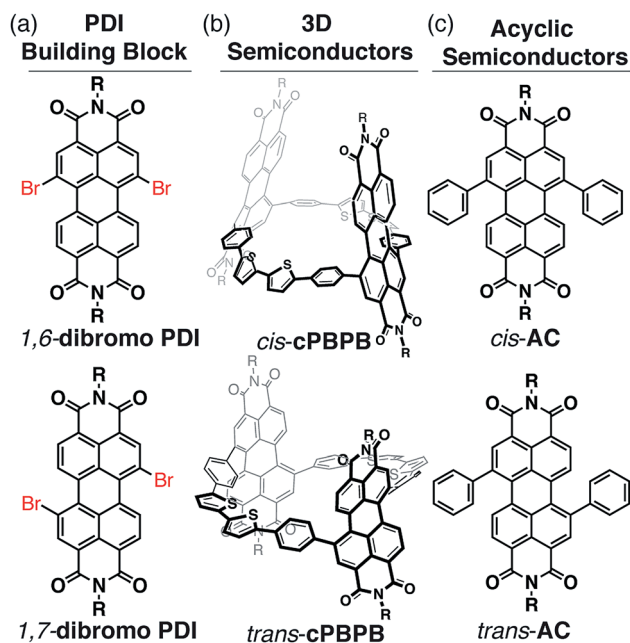


Fig. 1 Structures of (a) 1,6- and 1,7-dibromo PDI, with the *cis/trans* orientation indicated in red; (b) *cis-cPBPB* and *trans-cPBPB*; and (c) structures of acyclic PDI derivatives. *cis-* and *trans-*based semiconductors are derived from 1,6-dibromo PDI and 1,7-dibromo PDI, respectively. R = branched C₁₁H₂₃ side chains.

π - π coupling while allowing for synthetic flexibility to control their electronic properties.

Results

We utilize two types of perylene-3,4,9,10-tetracarboxylic diimide (PDI) macrocycles that differ in their connectivity to the phenyl-bithiophene-phenyl linker: the PDI and linker are in a *trans* orientation for *trans-cPBPB* and *cis* orientation for *cis-cPBPB* (Fig. 1b). *trans-cPBPB* incorporates a 1,7-substituted PDI isomer into the synthesis while *cis-cPBPB* comprises a 1,6-substituted PDI isomer (Fig. 1). We call these macrocycles **cPBPB**, where “c” = cyclic, **P** is diphenyl PDI, and **B** is bithiophene. We previously reported the synthesis of *trans-cPBPB*.⁴² We measure the device performance in OFETs, and show that electrical mobilities are three times higher in the *trans*-based devices than in the *cis*-based devices. We study the materials on a single molecule level with macrocyclic components, use control experiments, computations, and spectroscopy to determine that the difference in electron mobility in OFETs made with the two macrocyclic isomers is due to the difference in intramolecular conductivity. This study demonstrates that intramolecular carrier pathways affect electron transport in three-dimensional molecular solids.

We first investigate the impact from the *cis-* or *trans-*linkage on the electrical properties of OFETs made using *trans-* and *cis-cPBPB* (Fig. 2). Both *trans-cPBPB* and *cis-cPBPB* exhibit n-type characteristics and not p-type characteristics. To validate if the materials show any p-type characteristics, we set the source voltage at -80 V and swept the gate voltage to -80 V. From this measurement, we didn't observe any current in the negative

gate region, which confirms the material doesn't show p-type characteristics. The devices show some leakage current due to the large difference between the gate voltage when we sweep from 80 V to -20 V and the source-drain current (80 V).[†] The ESI[†] contains the output curves for the two macrocycles (Fig. S1[†]).

Fig. 2a and b display the current *versus* applied gate voltages (transfer curves) for a *trans* and *cis* device. We collected the data for these transfer curves using a source-drain voltage of 80 V while sweeping the gate voltage from -20 V to 80 V. The mobility was calculated in the saturation regime^{3,43} using $I_{DS} = (W/2L)C_i\mu(V_G - V_T)^2$, where W and L are the width and length of the channel, C_i (11.5 nF cm⁻²), μ , V_G , and V_T correspond to the capacitance per unit area of the gate insulator, the field effect mobility, the gate voltage, and the threshold voltage, respectively. We find the mobility in *trans-cPBPB* is three times that in *cis-cPBPB* (1.3×10^{-3} cm² V⁻¹ s⁻¹ versus 0.4×10^{-3} cm² V⁻¹ s⁻¹). We reproduce these mobility measurements across many samples. For example, we made ten devices with each isomer and found that the same values for the mobilities. Table 1 provides the averaged data for each macrocycle.

As morphology is known to have a profound effect on mobility, we first examined the film morphology using atomic force microscopy (AFM) to see if morphological differences could explain the difference in mobility.^{2,5,44,45} Both films were continuous and smooth, and had a room-mean-square roughness of 0.35 nm and 0.37 nm for *cis-cPBPB* and *trans-cPBPB*, respectively (Fig. 2c and d). The powder/thin-film X-ray diffraction (PXRD) of both films too shows no signs of crystallinity (Fig. S2[†]). Taken together, the lack of difference (and the featurelessness of) in the PXRD and AFM data for the two isomers reveals that the difference in mobility cannot be attributed to morphological or crystallinity differences. Therefore, any differences in packing between the two isomers would need to be on an extremely short length scale.

We then used density functional theory (DFT) calculations to probe the differences in the molecular conformations and structures for *trans-cPBPB* and *cis-cPBPB*. Fig. 3 contains the lowest energy structures for *cis-cPBPB* and *trans-cPBPB* determined from DFT using 6-31G/B3LYP level of computation. We see that the PDI units remain upright in *trans-cPBPB* while they bow inward toward the cavity in *cis-cPBPB*. The PDI-linker connection differs between the two isomers. The torsional angle is greater in the *cis* molecule relative to *trans-cPBPB*. This causes the PDI and linker to possess a relatively more orthogonal relationship, and decreases the electronic coupling in *cis-cPBPB* (Fig. 3a and b). The colors of the macrocycles support *trans-cPBPB* is more conjugated: *cis-cPBPB* is purple by visual inspection, and *trans-cPBPB* is black.

We next consider the packing of these macrocycles with the crystal structure of *trans-cPBPB* (shown in Fig. 3c and ESI[†]). We see that the macrocycles pack with the PDI face of one adjacent to that of another, though with opposite chirality.⁴⁶⁻⁴⁸ We were unable to obtain *cis-cPBPB*'s crystal structure, but anticipate a similar face-to-face packing, given the DFT-based structure presented here. The differences in the packing between the two isomers could result in an intermolecular effect on the



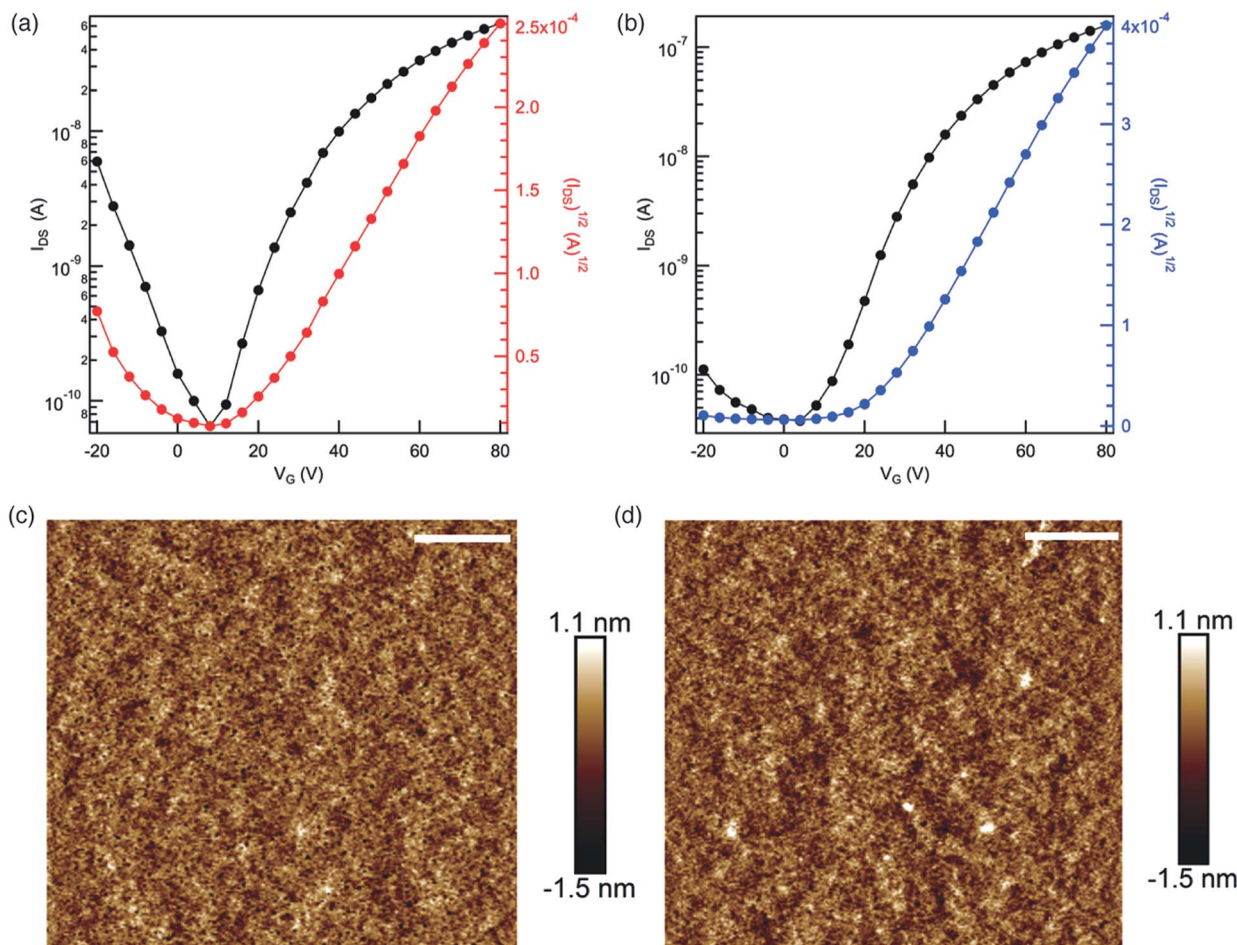


Fig. 2 Electrical characteristics and morphology of the cPBPB OFETs. (a) Transfer curve for *cis*-cPBPB; (b) transfer curve for *trans*-cPBPB. Device current (left axis, black) and square root of current (right axis, red or blue) measured as a function of gate voltage at a constant source-drain voltage of 80 V. The *trans*-cPBPB device has a higher current than the *cis*-cPBPB at a high and positive gate voltage, indicating a higher mobility for n-type carriers. (c) Height image for *cis*-cPBPB and (d) *trans*-cPBPB. Both films are continuous and smooth and have a root mean square roughness of 0.35 and 0.37 nm for the *cis* and *trans*-based devices, respectively. The scale bar is 1.0 μm .

conductivity that could also contribute to the difference in mobility, but we reiterate that the films are amorphous and featureless for each of the isomers.

In addition, it is known that molecular strain and rigidity can influence charge transport in macrocyclic semiconductors with the more strained systems having lower intermolecular coupling and hence lower intermolecular conductivity and lower mobility.⁴¹ We calculate the enthalpy difference between the macrocycle and an acyclic analog (*i.e.*, a homodesmotic

calculation^{28,49–51}) to assess the strain energy in *trans*-cPBPB and *cis*-cPBPB. We found only a small (2 kcal mol⁻¹) difference in strain energy and therefore conclude that this does not explain the difference in mobility. The ESI† contains the details of the calculations used to assess the strain energy.

As these macrocyclic materials are n-type semiconductors, we wondered if a difference in reduction potentials would explain the difference in mobility. We used cyclic voltammetry (CV) to estimate the lowest unoccupied molecular orbital

Table 1 Comparison of *trans*-cPBPB and *cis*-cPBPB^a

	Mobility $\mu \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$	LUMO level ^b (eV)	Optical gap ^c (eV)
<i>trans</i> -cPBPB	$(1.2 \pm 0.1) \times 10^{-3}$	-3.82	1.78
<i>cis</i> -cPBPB	$(0.4 \pm 0.1) \times 10^{-3}$	-3.79	1.85
<i>trans</i> -AC	$(1.5 \pm 0.3) \times 10^{-4}$	-3.74	2.10
<i>cis</i> -AC	$(1.9 \pm 0.3) \times 10^{-4}$	-3.74	2.10

^a CV, optical gap and FET performance for the two macrocycles and acyclic controls. ^b LUMO levels were estimated from onset of the first reduction peaks. ^c Optical band gaps were estimated from the onset of absorption.



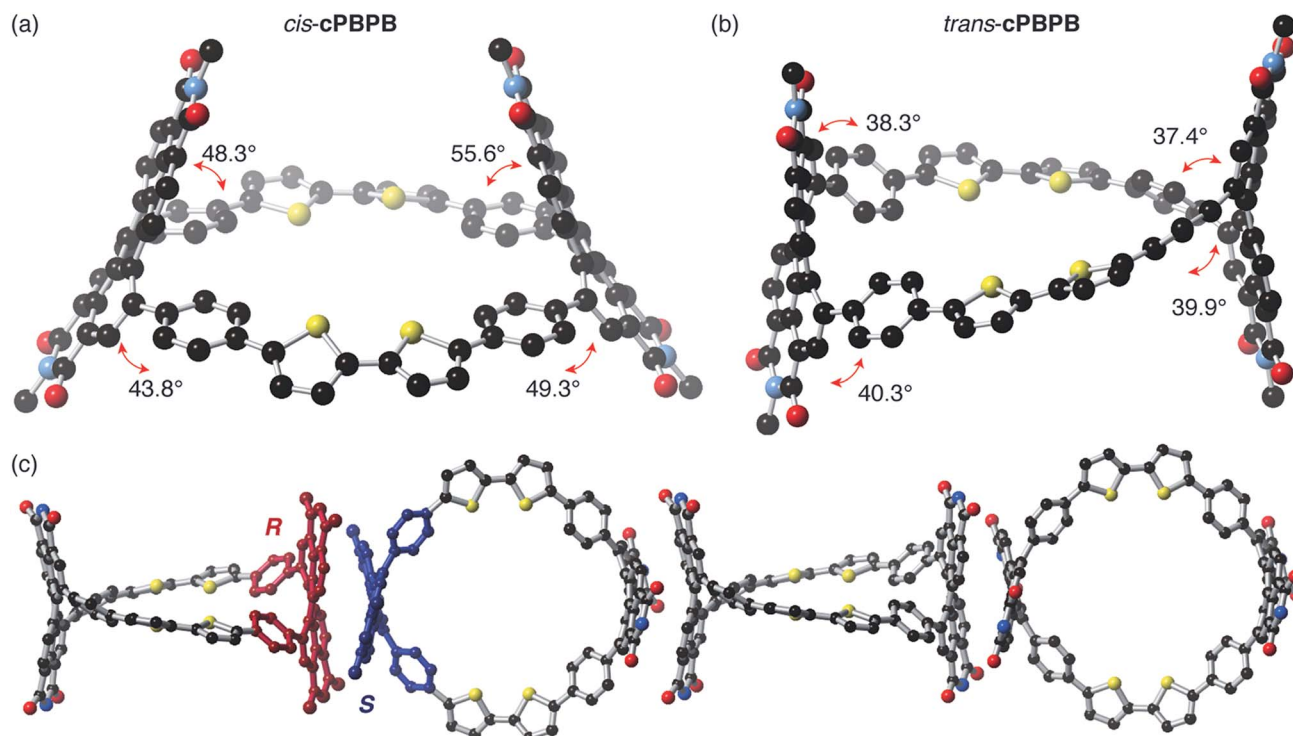


Fig. 3 Molecular structures obtained with DFT using 6.31G/B3LYP basis set. (a) *cis*-cBPBPB and (b) *trans*-cBPBPB. (c) SCXRD solid-state packing of *trans*-cBPBPB as viewed down the *a* axis. Blue and red are the two enantiomers of the diphenyl PDI packing down the axis. Red = oxygen, blue = nitrogen, black = carbon, and yellow = sulfur. Hydrogens and side chains have been removed for clarity.

(LUMO) energies for both *trans*- and *cis*-cBPBPB (Table 1, Fig. S3†). *trans*-cBPBPB and *cis*-cBPBPB have similar reduction potentials, as estimated from the onset of the first reduction peak.⁵² We also examined the electronic structure using UV-vis. The UV-vis spectrum suggests *trans*-cBPBPB is more conjugated. The lowest energy transition is at a lower energy in *trans*-cBPBPB than in *cis*-cBPBPB. Moreover, *trans*-cBPBPB has a smaller optical

gap than the *cis*-cBPBPB macrocycle (Table 1, Fig. S4†). This likely reflects greater orbital overlap, given the smaller torsional angle between the linker and the PDI (Fig. 3a and b).

We next evaluate the intramolecular conductivity by deconstructing the macrocycles into 1,6- and 1,7-diphenyl PDI monomers that possess two auropophilic amino groups on the aryl rings. We refer to these molecules as *trans*-DAPP and *cis*-DAPP (Fig. 4a and ESI III†). While the *cis* and *trans* PDI isomers are well known,^{53–56} the difference in intramolecular conduction between the *cis* and *trans* isomers has not been reported until now. The two auropophilic amino groups on the aryl rings bind the Au electrodes in the STM-BJ setup^{57–60} to form Au-DAPP-Au junctions (Fig. 4a). We found that *trans*-DAPP has a conductance nearly one order of magnitude higher than *cis*-DAPP at $\sim 8.6 \times 10^{-5} G_0$ compared with $\sim 1.0 \times 10^{-5} G_0$ (Fig. 4b), where $G_0 = e^2/h$ is the conductance quantum. Fig. S5† contains the two-dimensional histograms for *cis*- and *trans*-DAPP and details for the experimental setup.

Because the STM-BJ studies determined that *trans*-substituted PDI molecular junctions are better conductors than *cis*-substituted PDI junctions, we hypothesized that the difference in the mobilities seen for *trans*- and *cis*-cBPBPB based OFETs is due to the *trans/cis* substitution patterns. The experiments described next find that the substitution patterns in the acyclic subunits do not explain the differences in mobility between the two three-dimensional macrocyclic semi-conductors, *cis*-cBPBPB and *trans*-cBPBPB.

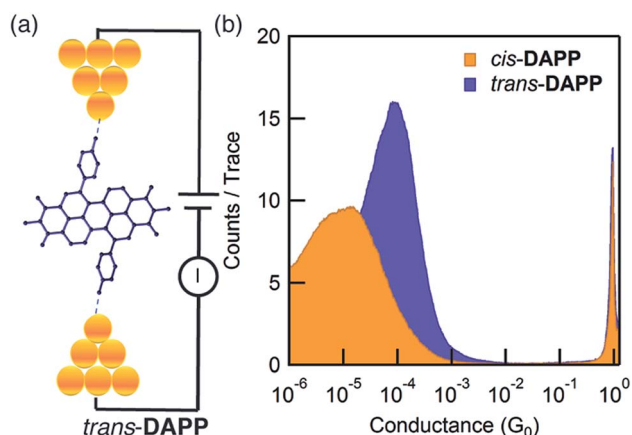


Fig. 4 (a) Schematic of a single-molecule junction showing *trans*-DAPP in the break junction. The diphenyl PDI contains two auropophilic amino groups on the aryl rings to bind the gold electrodes in the junction; (b) logarithmic conductance histograms for *cis*-DAPP (yellow) and *trans*-DAPP (purple) measured with an applied bias of 450 mV in a 1,2,4-trichlorobenzene solution.



We synthesized the acyclic relatives of *trans*- and *cis*-cPBPB, *cis*- and *trans*-AC, which comprise a diphenyl PDI substituted in a *cis* and *trans* orientation (Fig. 1c). We made OFETs using *cis*- and *trans*-AC, and find that the two have similar averaged electron mobilities: $1.9 \times 10^{-4} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ and $1.5 \times 10^{-4} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ for *cis*-AC and *trans*-AC, respectively (see Table 1, ESI Table S1 and Fig. S6† for details). We also studied the film morphology using AFM, and both films were smooth, with a root mean square roughness of 0.43 and 0.45 nm for *cis*- and *trans*-AC, respectively (Fig. S7†). Since *cis*-AC and *trans*-AC show similar mobilities in OFETs, the *cis* and *trans* substitution pattern alone is not the reason for the difference in the performance found in the macrocyclic systems.

Conclusions

Both *trans*-cPBPB and *trans*-AC possess a *trans* linkage, suggesting higher intramolecular conductivity than the *cis* analogues from the STM-BJ measurements. Yet OFET devices from either *trans*- or *cis*-AC show similar electron mobilities, while electron mobilities from *trans*-cPBPB or *cis*-cPBPB macrocycles show marked differences in their mobilities. From this data, we conclude that the substitution pattern in the subunits is not responsible for the difference in charge transport in the *acyclic controls*, but influences charge transport for the relatively complex three dimensional semiconducting macrocycles. *trans*-cPBPB is more conjugated than *cis*-cPBPB, as reflected in the UV-vis data, suggesting that the intramolecular conductivity is higher in the *trans*-based macrocycle. Together, the acyclic control data, STM-BJ measurements, and spectroscopy demonstrate that intramolecular carrier pathways affect charge transport as the complexity of the molecule increases in molecular solids. For both isomers, the films are featureless, flat, and amorphous, implying that the morphology of the films and the crystal packing is not responsible for the difference in mobility. This study reveals the importance of not just intermolecular interactions and reorganization energy as conditions for electrical conduction in OFETs but also shows the importance of intramolecular conduction.

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Conflicts of interest

There are no conflicts to declare.

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Notes and references

‡ The current seen from the negative voltage is related to leakage current and does not represent an ambipolar device.

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